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Team Nexperia

PDTA143E series

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 4.7 k Ω

Rev. 8 — 8 December 2011

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			NPN	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTA143EE	SOT416	SC-75	-	PDTC143EE	ultra small
PDTA143EM	SOT883	SC-101	-	PDTC143EM	leadless ultra small
PDTA143ET	SOT23	-	TO-236AB	PDTC143ET	small
PDTA143EU	SOT323	SC-70	-	PDTC143EU	very small

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8.0	1	1.2	



2. Pinning information

Table 3. **Pinning** Pin Simplified outline **Graphic symbol Description** SOT23; SOT323; SOT416 1 input (base) 3 GND (emitter) 2 3 output (collector) 2 006aaa144 sym003 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PDTA143EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA143EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTA143ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA143EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTA143EE	01
PDTA143EM	DL
PDTA143ET	*01
PDTA143EU	*01

[1] * = placeholder for manufacturing site code

sym003

5. Limiting values

Table 6. Limiting values

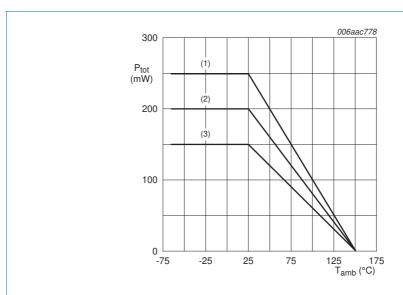
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	М	in	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-		-50	V
V_{CEO}	collector-emitter voltage	open base	-		-50	V
V_{EBO}	emitter-base voltage	open collector	-		-10	V
V_{I}	input voltage					
	positive		-		+10	V
	negative		-		-30	V
Io	output current		-		-100	mA
I _{CM}	peak collector current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-		-100	mA
P _{tot}	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$				
	PDTA143EE (SOT416)		[1][2] _		150	mW
	PDTA143EM (SOT883)		[2][3]		250	mW
	PDTA143ET (SOT23)		[1] -		250	mW
	PDTA143EU (SOT323)		[1] -		200	mW
T _j	junction temperature		-		150	°C
T _{amb}	ambient temperature		-6	§5	+150	°C
T_{stg}	storage temperature		-6	§5	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70 μm copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

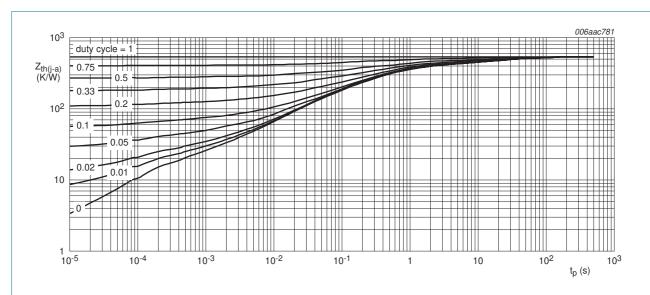
Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

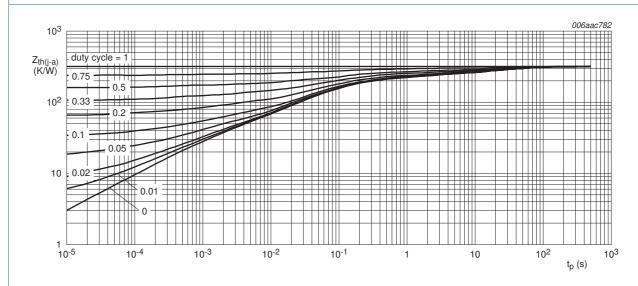
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTA143EE (SOT416)		[1][2]	-	830	K/W
	PDTA143EM (SOT883)		[2][3]	-	500	K/W
	PDTA143ET (SOT23)		[1] -	-	500	K/W
	PDTA143EU (SOT323)		[1] -	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143EE (SOT416); typical values



FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143EM (SOT883); typical values

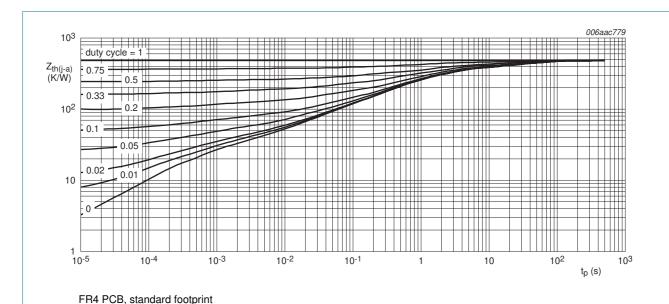


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ET (SOT23); typical values

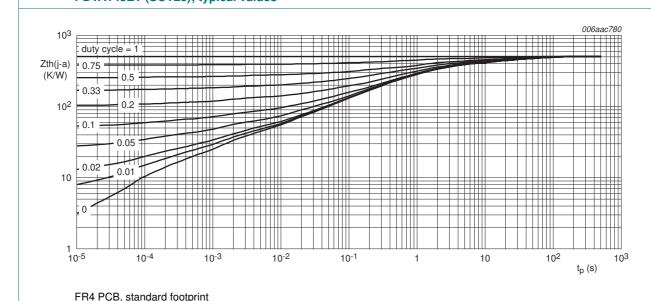


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143EU (SOT323); typical values

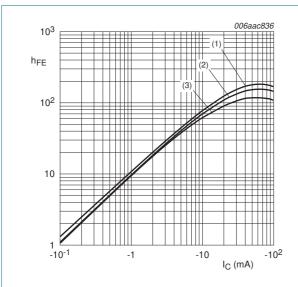
7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	- 5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-900	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10$ mA; $I_B = -0.5$ mA	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-1.1	-0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -0.3 \text{ V};$ $I_{C} = -20 \text{ mA}$	-2.5	-1.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8.0	1	1.2	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}; $ [1] $f = 100 \text{ MHz}$	-	180	-	MHz

^[1] Characteristics of built-in transistor



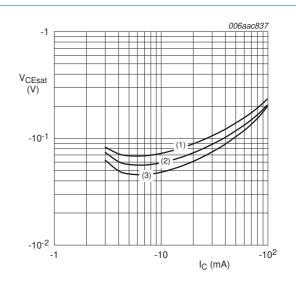
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 6. DC current gain as a function of collector current; typical values



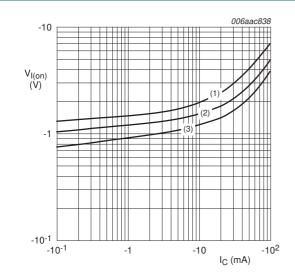
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



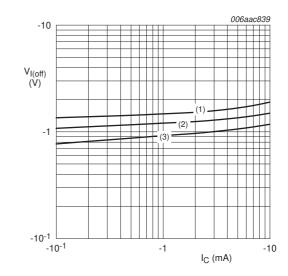
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Off-state input voltage as a function of collector current; typical values

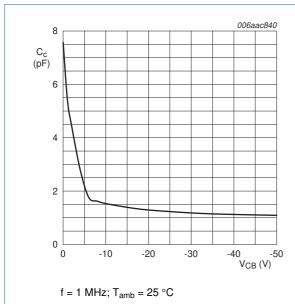


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

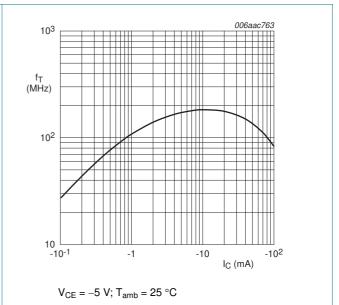


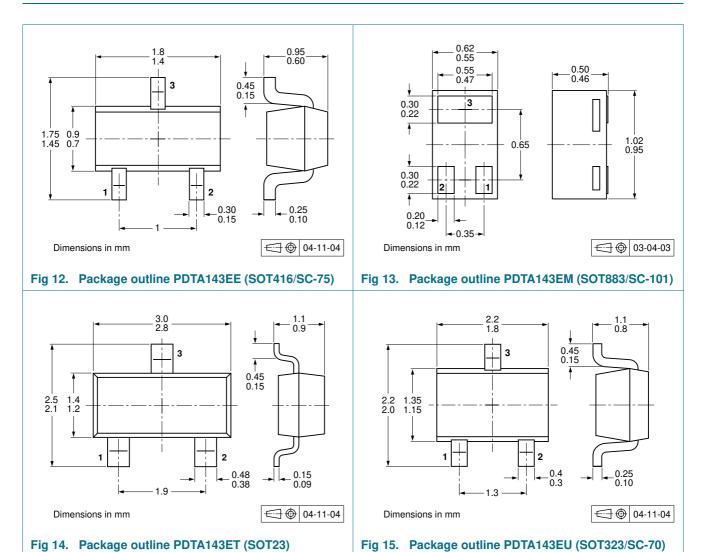
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity	
			3000	5000	10000
PDTA143EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA143EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA143ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTA143EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

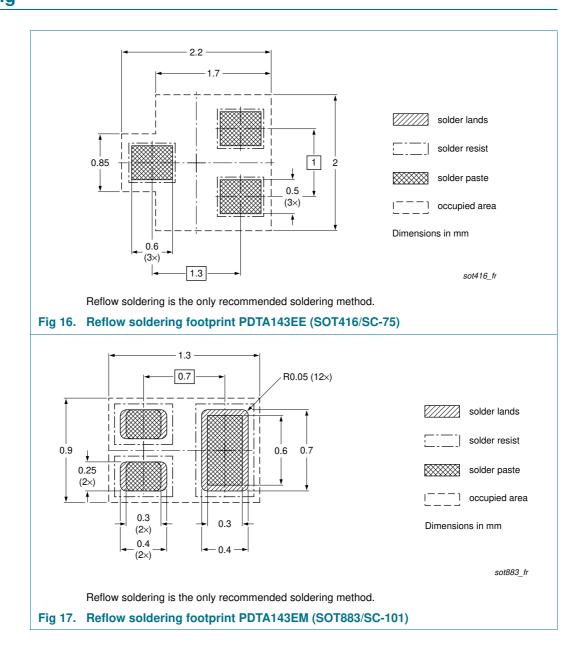
[1] For further information and the availability of packing methods, see Section 14.

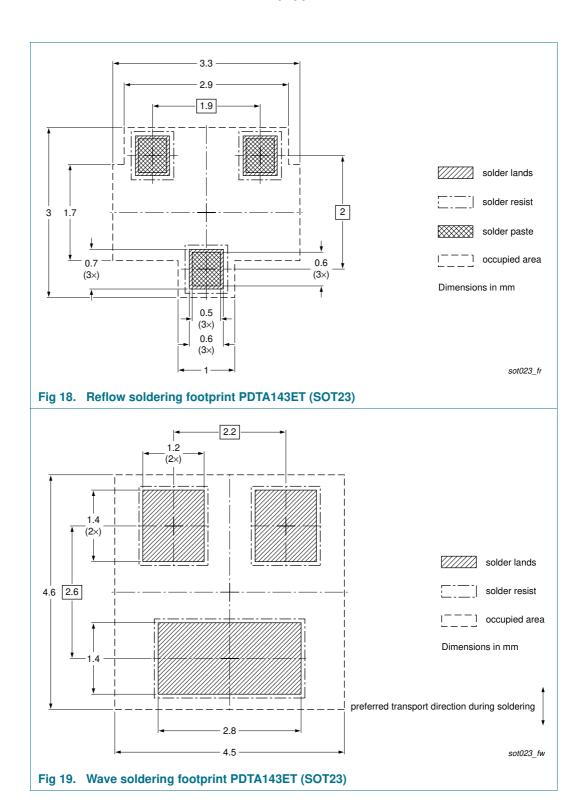
PDTA143E_SER

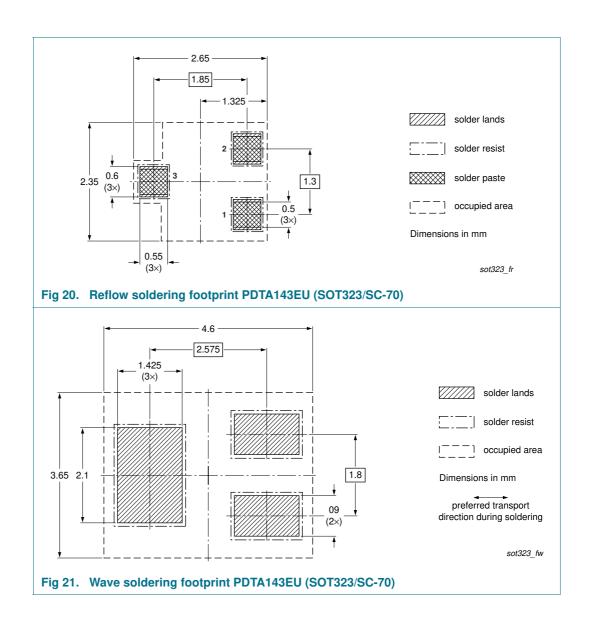
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11. Soldering







12. Revision history

Table 10. Revision history

Release date	Data sheet status	Change notice	Supersedes		
20111208	Product data sheet	-	PDTA143E_SERIES v.7		
		edesigned to comply w	ith the new identity		
 Legal texts have been adapted to the new company name where appropriate. 					
 Type numbers PDTA143EEF, PDTA143EK and PDTA143ES removed. 					
Section 1 "Product profile": updated					
Section 3 "Or	Section 3 "Ordering information": added				
Section 4 "Marking": updated					
• Figure 1 to 11: added					
Section 6 "The section 1.5" Section 1.	nermal characteristics": upd	ated			
			t voltage, $V_{i(off)}$ redefined to		
Section 8 "Te	est information": added				
Section 9 "Page 1.5"	ackage outline": superseded	by minimized packag	e outline drawings		
Section 10 "F	Packing information": added				
Section 11 "S	Soldering": added				
Section 13 "L	<u>egal information"</u> : updated				
20040804	Product data sheet	-	PDTA143E_SERIES v.6		
20030908	Product specification	-	PDTA143E_SERIES v.5		
20030411	Product specification				
	20111208 The format of guidelines of Legal texts how Type number Section 1 "Properties of Section 3" On Section 4" Months of Section 6" The Table 8" Change of Section 8" Testion 6" Testion 6" Testion 9" Properties of Section 9" Properties of Section 10" For Section 11" Section 11" Section 11" Section 13" Legislation 10" For Section 11" Section 13" Legislation 13"	 The format of this document has been reguidelines of NXP Semiconductors. Legal texts have been adapted to the need to type numbers PDTA143EEF, P	Product data sheet The format of this document has been redesigned to comply wing guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where Type numbers PDTA143EEF, PDTA143EK and PDTA143ES resection 1 "Product profile": updated Section 3 "Ordering information": added Section 4 "Marking": updated Figure 1 to 11: added Section 6 "Thermal characteristics": updated Table 8 "Characteristics": Vi(on) redefined to VI(on) on-state input VI(off) off-state input voltage, ICEO updated, fr added Section 8 "Test information": added Section 9 "Package outline": superseded by minimized package Section 10 "Packing information": added Section 11 "Soldering": added Section 13 "Legal information": updated Product data sheet Product specification -		

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTA143E_SER

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PDTA143E series

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 4.7 k Ω

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PDTA143E series

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 4.7 k Ω

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